TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOS V-H)

TPCC8001-H

High-Efficiency DC-DC Converter Applications
Notebook PC Applications
Portable Equipment Applications

- · Small footprint due to a small and thin package
- · High-speed switching
- Small gate charge: Q_{SW} = 7.1 nC (typ.)
- Low drain-source ON-resistance:

 $R_{DS\;(ON)}$ = 7.6 m Ω (typ.) (V_{GS} = 4.5 V)

- High forward transfer admittance: |Yfs| = 65 S (typ.)
- Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 30 \text{ V)}$
- Enhancement mode: V_{th} = 1.5 to 2.5 V (V_{DS} = 10 V, I_D = 1 mA)

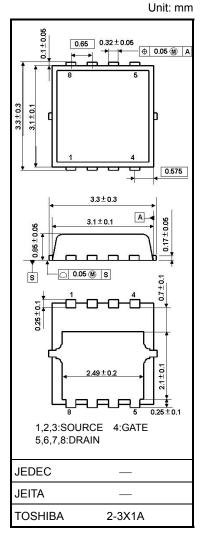
Absolute Maximum Ratings (Ta = 25°C)

Characte	eristic	Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	30	V	
Drain-gate voltage (F	$R_{GS} = 20 \text{ k}\Omega$	V_{DGR}	30	V	
Gate-source voltage		V _{GSS}	±20	٧	
Drain current	DC (Note 1)	ID	22	Α	
Diain current	Pulsed (Note 1)	I_{DP}	66	A	
Drain power dissipati	on (Tc = 25°C)	P_{D}	30	W	
Drain power dissipati	on (t = 10 s) (Note 2a)	PD	1.9	W	
Drain power dissipati	on (t = 10 s) (Note 2b)	PD	0.7	W	
Single-pulse avalanc	he energy (Note 3)	E _{AS}	126	mJ	
Avalanche current		I _{AR}	22	Α	
Repetitive avalanche	energy c = 25°C) (Note 4)	E _{AR}	2.1	mJ	
Channel temperature	:	T _{ch}	150	°C	
Storage temperature	range	T _{stg}	-55 to 150	°C	

Note: For Notes 1 to 4, refer to the next page.

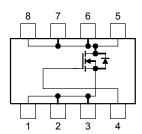
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.02 g (typ.)

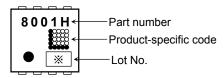
Circuit Configuration



Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc = 25°C)	R _{th (ch-c)}	4.2	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th (ch-a)}	66	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	180	°C/W

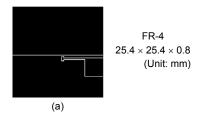
Marking (Note 5)

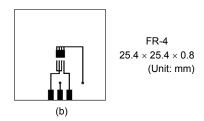


Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)

(b) Device mounted on a glass-epoxy board (b)





Note 3: $V_{DD}=24~V,~T_{Ch}=25^{\circ}C$ (initial), $L=200~\mu H,~R_{G}=25~\Omega,~I_{AR}=22~A$

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: * Weekly code: (Three digits)



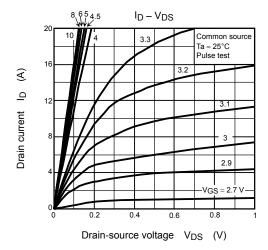


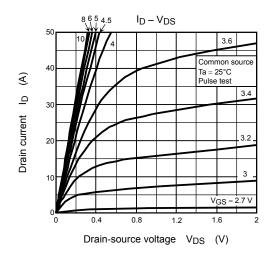
Electrical Characteristics (Ta = 25°C)

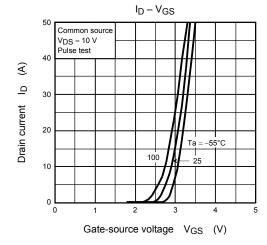
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	Sate leakage current		$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cutoff curre	ent	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$	_	_	10	μА
Drain-source bre	akdowa voltogo	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	30	_	_	V
Diain-source bre	akuowii voitage	V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	— — 10 30 — — 15 — — 1.5 — 2.5 — 7.6 10.6 — 5.5 8.3 33 65 — — 1900 2500 — 110 170 — 400 — — 1.0 1.5 — 2.8 — — 9.8 — — 5.9 — — 27 —	V		
Gate threshold vo	oltage	V _{th}	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$	1.5	_	2.5	V
Drain-source ON	rosistanos	Pro (ON)	$V_{GS} = 4.5 \text{ V}, I_D = 11 \text{ A}$	_	7.6	10.6	- mΩ
Diain-source Oiv	-resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 11 A	- 5.5 8.3 33 65 - - 1900 2500 - 110 170 - 400 -	11122		
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, I_{D} = 11 \text{ A}$	33	65	_	S
Input capacitance	9	C _{iss}		_	1900	2500	pF
Reverse transfer	capacitance	C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	110	170	
Output capacitan	се	C _{oss}		_	400	_	
Gate resistance				1.0	1.5	Ω	
	Rise time	t _r	V _{GS} 10 V	_	2.8	_	ns
Switching time	Turn-on time	t _{on}		_	9.8	_	
	Fall time	t _f		_	5.9	_	
	Turn-off time	t _{off}	$V_{DD} \approx 15 \text{ V}$ Duty \leq 1%, $t_W = 10 \mu\text{s}$	_	27	_	
Total gate charge			$V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 22 \text{ A}$	_	27	_	
(gate-source plus	gate-drain)	Qg	$V_{DD} \approx 24 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 22 \text{ A}$	_	14.3	_	
Gate-source charge 1		Q _{gs1}		_	6.8	_	nC
Gate-drain ("Miller") charge		Q _{gd}	$V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 22 \text{ A}$		4.3		
Gate switch char	ge	Q _{SW}		_	7.1	_	

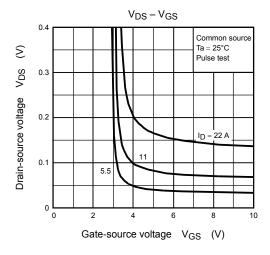
Source-Drain Ratings and Characteristics (Ta = 25°C)

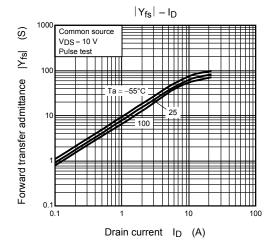
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	I _{DRP}	_	_	_	66	Α
Forward voltage (diode)			V _{DSF}	$I_{DR} = 22 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.2	٧

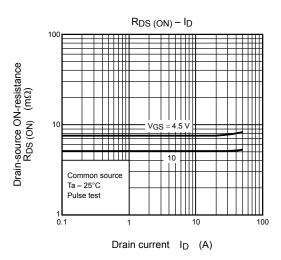




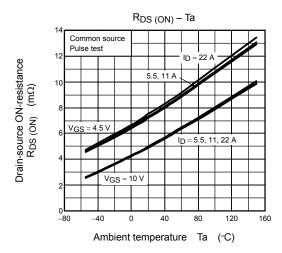


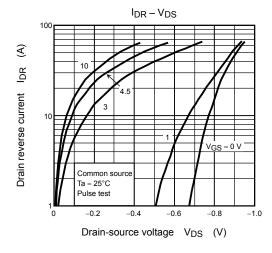


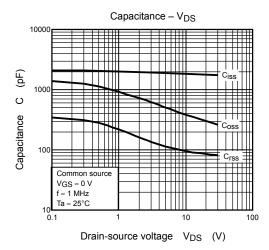


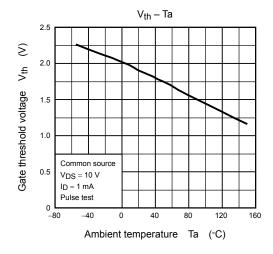


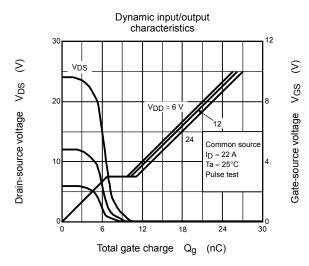
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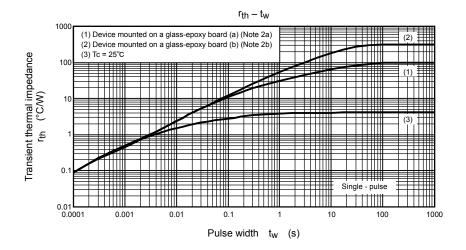


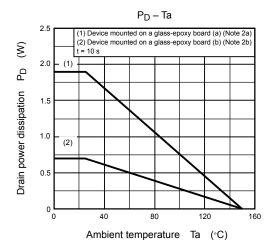


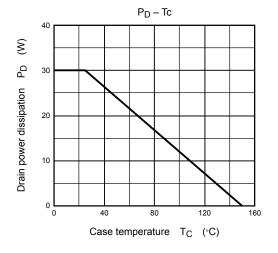


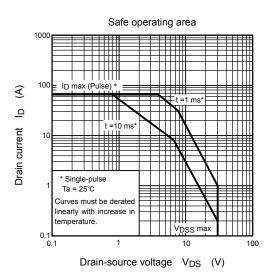


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